

DATA SHEET

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74AHC3G14; 74AHCT3G14 Inverting Schmitt trigger

Product specification
Supersedes data of 2003 Nov 27

2004 Oct 18

Inverting Schmitt trigger

74AHC3G14; 74AHCT3G14

FEATURES

- Symmetrical output impedance
- High noise immunity
- ESD protection:
 - HBM EIA/JESD22-A114-B exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V
 - CDM EIA/JESD22-C101 exceeds 500 V.
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$.

APPLICATIONS

- Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators.

DESCRIPTION

The 74AHC3G/AHCT3G14 is a high-speed Si-gate CMOS device.

The 74AHC3G/AHCT3G14 provides three inverting buffers with Schmitt-trigger action. These devices are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

QUICK REFERENCE DATA

GND = 0 V; $T_{\text{amb}} = 25\text{ }^{\circ}\text{C}$; $t_r = t_f \leq 3.0\text{ ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			AHC3G14	AHCT3G14	
$t_{\text{PHL}}/t_{\text{PLH}}$	propagation delay A to Y	$C_L = 15\text{ pF}$; $V_{\text{CC}} = 5\text{ V}$	3.2	4.1	ns
C_I	input capacitance		1.5	1.5	pF
C_{PD}	power dissipation capacitance	$C_L = 15\text{ pF}$; $f = 1\text{ MHz}$; notes 1 and 2	10	12	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{\text{PD}} \times V_{\text{CC}}^2 \times f_i \times N + \Sigma(C_L \times V_{\text{CC}}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = number of inputs switching;

$\Sigma(C_L \times V_{\text{CC}}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = \text{GND to } V_{\text{CC}}$.

FUNCTION TABLE

See note 1.

INPUT	OUTPUT
nA	nY
L	H
H	L

Note

1. H = HIGH voltage level;
L = LOW voltage level.

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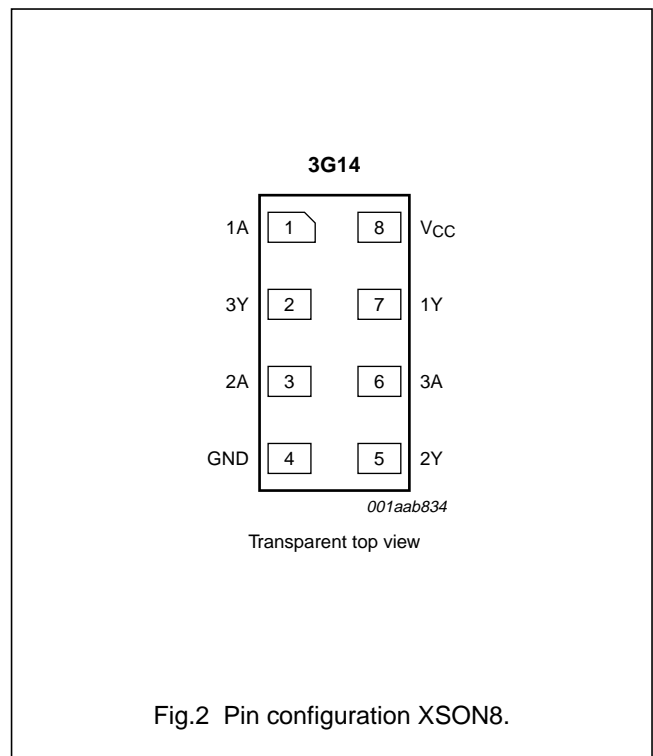
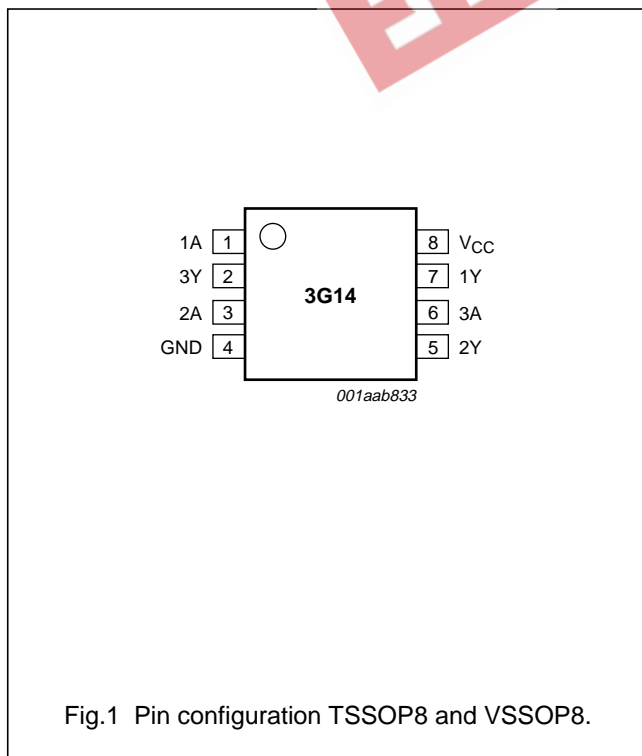
74AHC3G14; 74AHCT3G14

ORDERING INFORMATION

TYPE NUMBER	PACKAGE					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING
74AHC3G14DP	-40 °C to +125 °C	8	TSSOP8	plastic	SOT505-2	A14
74AHCT3G14DP	-40 °C to +125 °C	8	TSSOP8	plastic	SOT505-2	C14
74AHC3G14DC	-40 °C to +125 °C	8	VSSOP8	plastic	SOT765-1	A14
74AHCT3G14DC	-40 °C to +125 °C	8	VSSOP8	plastic	SOT765-1	C14
74AHC3G14GM	-40 °C to +125 °C	8	XSON8	plastic	SOT833-1	A14
74AHCT3G14GM	-40 °C to +125 °C	8	XSON8	plastic	SOT833-1	C14

PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	3Y	data output
3	2A	data input
4	GND	ground (0 V)
5	2Y	data output
6	3A	data input
7	1Y	data output
8	V _{CC}	supply voltage



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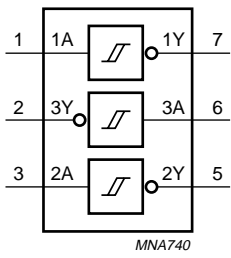


Fig.3 Logic symbol.

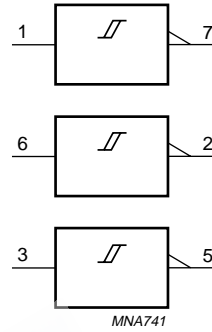


Fig.4 IEC logic symbol.

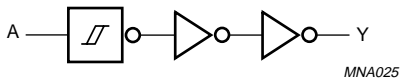


Fig.5 Logic diagram (one driver).

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74AHC3G			74AHCT3G			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
V_{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
V_I	input voltage		0	–	5.5	0	–	5.5	V
V_O	output voltage		0	–	V_{CC}	0	–	V_{CC}	V
T_{amb}	operating ambient temperature	see DC and AC characteristics per device	–40	+25	+125	–40	+25	+125	°C

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		–0.5	+7.0	V
V_I	input voltage		–0.5	+7.0	V
I_{IK}	input diode current	$V_I < -0.5$ V	–	–20	mA
I_{OK}	output diode current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V; note 1	–	±20	mA
I_O	output source or sink current	-0.5 V < V_O < $V_{CC} + 0.5$ V	–	±25	mA
I_{CC}, I_{GND}	V_{CC} or GND current		–	±75	mA
T_{stg}	storage temperature		–65	+150	°C
P_D	power dissipation	$T_{amb} = -40$ °C to +125 °C	–	250	mW

Note

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS

Type 74AHC3G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = 25 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = -50 μA	2.0	1.9	2.0	-	V
		I _O = -50 μA	3.0	2.9	3.0	-	V
		I _O = -50 μA	4.5	4.4	4.5	-	V
		I _O = -4.0 mA	3.0	2.58	-	-	V
		I _O = -8.0 mA	4.5	3.94	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 50 μA	2.0	-	0	0.1	V
		I _O = 50 μA	3.0	-	0	0.1	V
		I _O = 50 μA	4.5	-	0	0.1	V
		I _O = 4.0 mA	3.0	-	-	0.36	V
		I _O = 8.0 mA	4.5	-	-	0.36	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	5.5	-	-	0.1	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	-	-	1.0	μA
C _I	input capacitance		-	-	1.5	10	pF
T_{amb} = -40 °C to +85 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = -50 μA	2.0	1.9	-	-	V
		I _O = -50 μA	3.0	2.9	-	-	V
		I _O = -50 μA	4.5	4.4	-	-	V
		I _O = -4.0 mA	3.0	2.48	-	-	V
		I _O = -8.0 mA	4.5	3.8	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 50 μA	2.0	-	-	0.1	V
		I _O = 50 μA	3.0	-	-	0.1	V
		I _O = 50 μA	4.5	-	-	0.1	V
		I _O = 4.0 mA	3.0	-	-	0.44	V
		I _O = 8.0 mA	4.5	-	-	0.44	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	5.5	-	-	1.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	-	-	10	μA
C _I	input capacitance		-	-	-	10	pF

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 °C to +125 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} I _O = -50 μA	2.0	1.9	-	-	V
		I _O = -50 μA	3.0	2.9	-	-	V
		I _O = -50 μA	4.5	4.4	-	-	V
		I _O = -4.0 mA	3.0	2.40	-	-	V
		I _O = -8.0 mA	4.5	3.70	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} I _O = 50 μA	2.0	-	-	0.1	V
		I _O = 50 μA	3.0	-	-	0.1	V
		I _O = 50 μA	4.5	-	-	0.1	V
		I _O = 4.0 mA	3.0	-	-	0.55	V
		I _O = 8.0 mA	4.5	-	-	0.55	V
I _{LI}	input leakage current	V _I = V _{CC} or GND	5.5	-	-	2.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	-	-	40	μA
C _I	input capacitance		-	-	-	10	pF

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Type 74AHCT3G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = 25 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	4.5	4.4	4.5	–	V
		I _O = –50 μA I _O = –8.0 mA	4.5	3.94	–	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	4.5	–	0	0.1	V
		I _O = 50 μA I _O = 8.0 mA	4.5	–	–	0.36	V
I _{LI}	input leakage current	V _I = V _{IH} or V _{IL}	5.5	–	–	0.1	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	–	–	1.0	μA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = 3.4 V; other inputs at V _{CC} or GND; I _O = 0 A	5.5	–	–	1.35	mA
C _I	input capacitance		–	–	1.5	10	pF
T_{amb} = –40 °C to +85 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	4.5	4.4	–	–	V
		I _O = –50 μA I _O = –8.0 mA	4.5	3.8	–	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	4.5	–	–	0.1	V
		I _O = 50 μA I _O = 8.0 mA	4.5	–	–	0.44	V
I _{LI}	input leakage current	V _I = V _{IH} or V _{IL}	5.5	–	–	1.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	–	–	10	μA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = 3.4 V; other inputs at V _{CC} or GND; I _O = 0 A	5.5	–	–	1.5	mA
C _I	input capacitance		–	–	–	10	pF
T_{amb} = –40 °C to +125 °C							
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	4.5	4.4	–	–	V
		I _O = –50 μA I _O = –8.0 mA	4.5	3.70	–	–	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	4.5	–	–	0.1	V
		I _O = 50 μA I _O = 8.0 mA	4.5	–	–	0.55	V
I _{LI}	input leakage current	V _I = V _{IH} or V _{IL}	5.5	–	–	2.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	5.5	–	–	40	μA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = 3.4 V; other inputs at V _{CC} or GND; I _O = 0 A	5.5	–	–	1.5	mA
C _I	input capacitance		–	–	–	10	pF

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TRANSFER CHARACTERISTICS

Type 74AHC3G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = 25 °C							
V _{T+}	positive-going threshold	see Figs 6 and 7	3.0	–	–	2.2	V
			4.5	–	–	3.15	V
			5.5	–	–	3.85	V
V _{T-}	negative-going threshold	see Figs 6 and 7	3.0	0.9	–	–	V
			4.5	1.35	–	–	V
			5.5	1.65	–	–	V
V _H	hysteresis (V _{T+} – V _{T-})	see Figs 6 and 7	3.0	0.3	–	1.2	V
			4.5	0.4	–	1.4	V
			5.5	0.5	–	1.6	V
T_{amb} = –40 °C to +85 °C							
V _{T+}	positive-going threshold	see Figs 6 and 7	3.0	–	–	2.2	V
			4.5	–	–	3.15	V
			5.5	–	–	3.85	V
V _{T-}	negative-going threshold	see Figs 6 and 7	3.0	0.9	–	–	V
			4.5	1.35	–	–	V
			5.5	1.65	–	–	V
V _H	hysteresis (V _{T+} – V _{T-})	see Figs 6 and 7	3.0	0.3	–	1.2	V
			4.5	0.4	–	1.4	V
			5.5	0.5	–	1.6	V
T_{amb} = –40 °C to +125 °C							
V _{T+}	positive-going threshold	see Figs 6 and 7	3.0	–	–	2.2	V
			4.5	–	–	3.15	V
			5.5	–	–	3.85	V
V _{T-}	negative-going threshold	see Figs 6 and 7	3.0	0.9	–	–	V
			4.5	1.35	–	–	V
			5.5	1.65	–	–	V
V _H	hysteresis (V _{T+} – V _{T-})	see Figs 6 and 7	3.0	0.25	–	1.2	V
			4.5	0.35	–	1.4	V
			5.5	0.45	–	1.6	V

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Type 74AHCT3G14

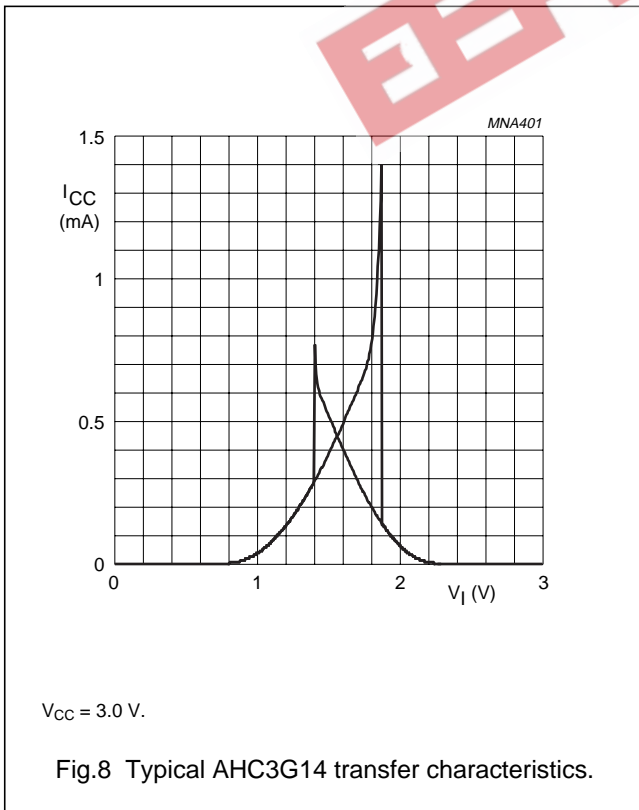
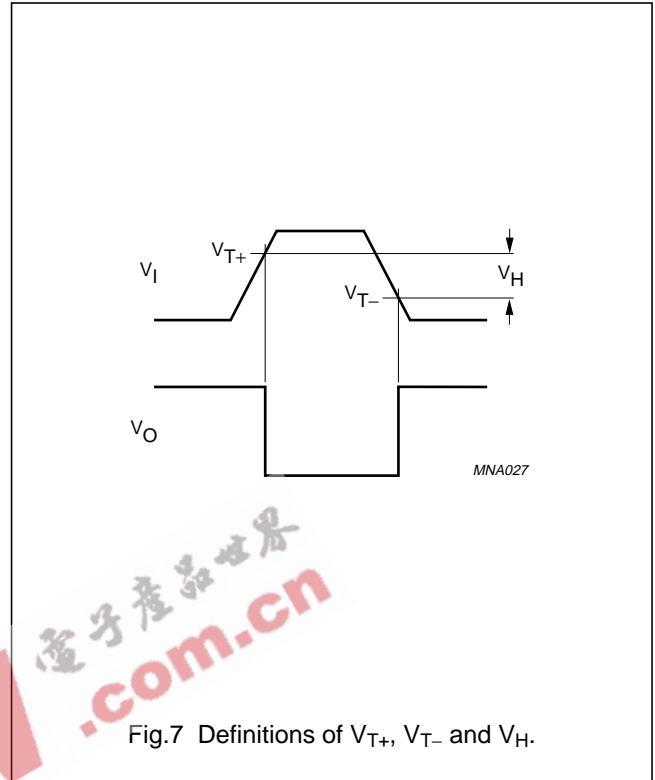
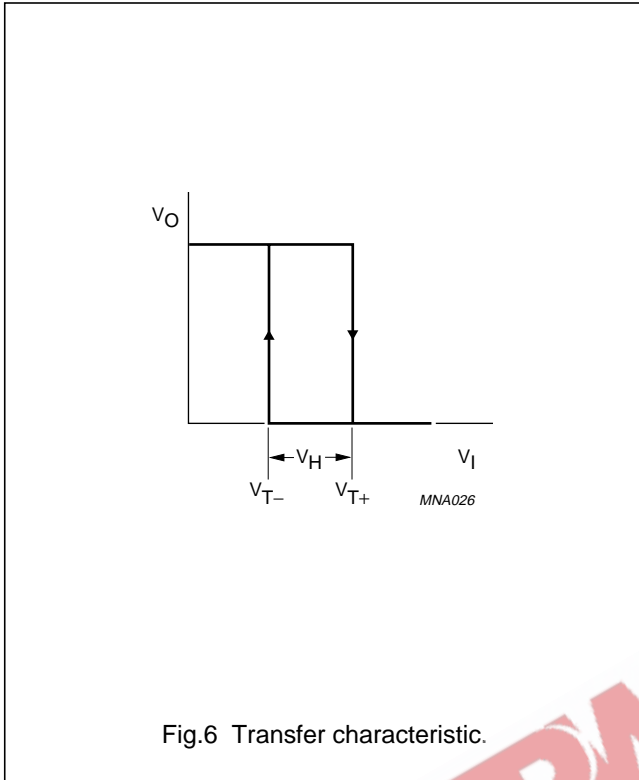
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = 25 °C							
V _{T+}	positive-going threshold	see Figs 6 and 7	4.5	–	–	2.0	V
			5.5	–	–	2.0	V
V _{T-}	negative-going threshold	see Figs 6 and 7	4.5	0.5	–	–	V
			5.5	0.6	–	–	V
V _H	hysteresis (V _{T+} – V _{T-})	see Figs 6 and 7	4.5	0.4	–	1.4	V
			5.5	0.4	–	1.6	V
T_{amb} = –40 °C to +85 °C							
V _{T+}	positive-going threshold	see Figs 6 and 7	4.5	–	–	2.0	V
			5.5	–	–	2.0	V
V _{T-}	negative-going threshold	see Figs 6 and 7	4.5	0.5	–	–	V
			5.5	0.6	–	–	V
V _H	hysteresis (V _{T+} – V _{T-})	see Figs 6 and 7	4.5	0.4	–	1.4	V
			5.5	0.4	–	1.6	V
T_{amb} = –40 °C to +125 °C							
V _{T+}	positive-going threshold	see Figs 6 and 7	4.5	–	–	2.0	V
			5.5	–	–	2.0	V
V _{T-}	negative-going threshold	see Figs 6 and 7	4.5	0.5	–	–	V
			5.5	0.6	–	–	V
V _H	hysteresis (V _{T+} – V _{T-})	see Figs 6 and 7	4.5	0.35	–	1.4	V
			5.5	0.35	–	1.6	V

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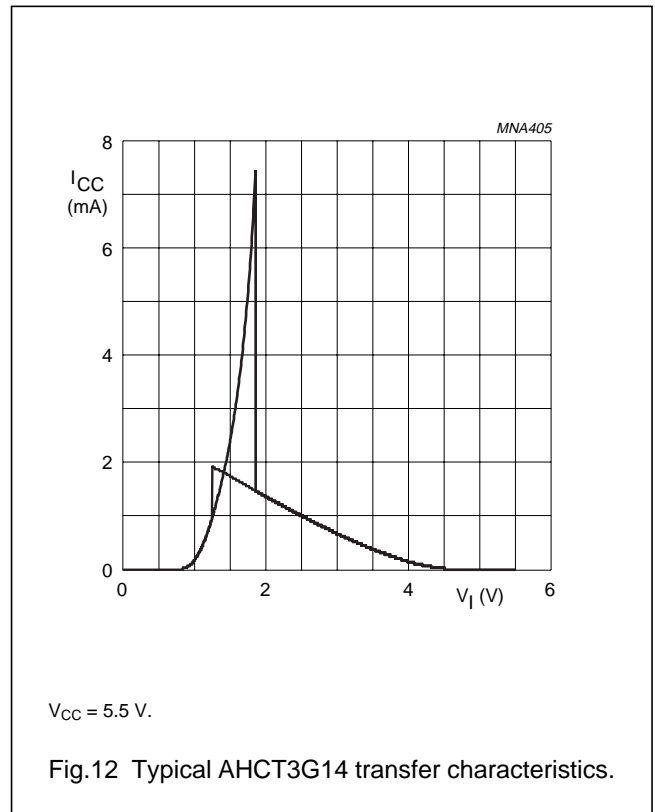
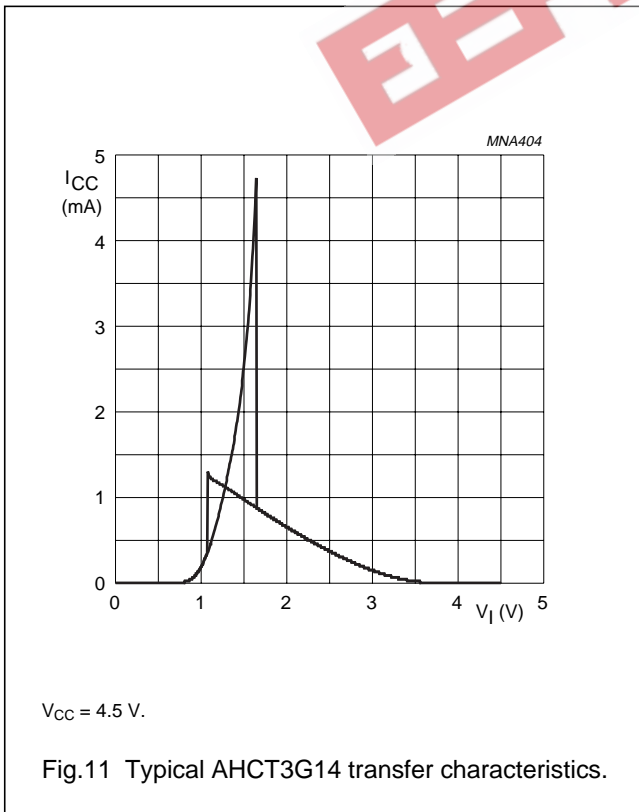
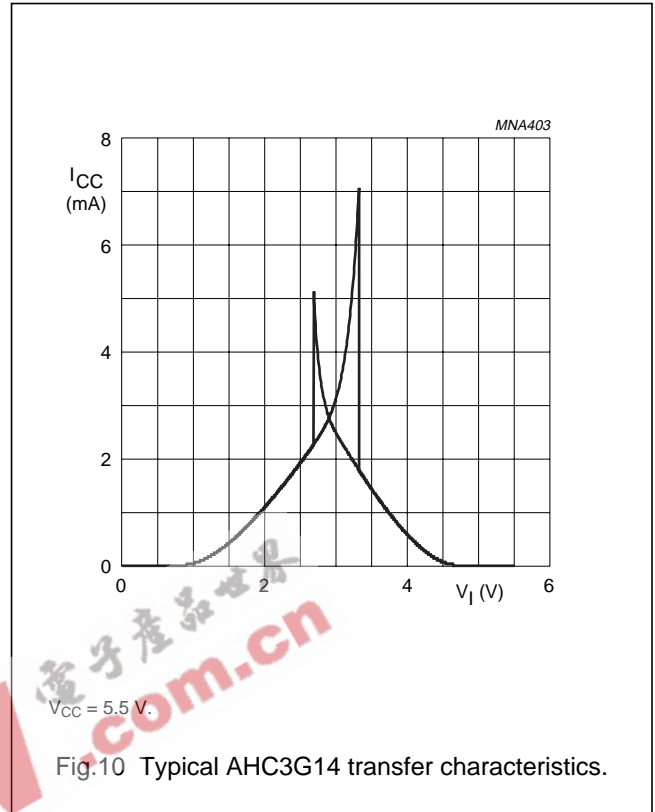
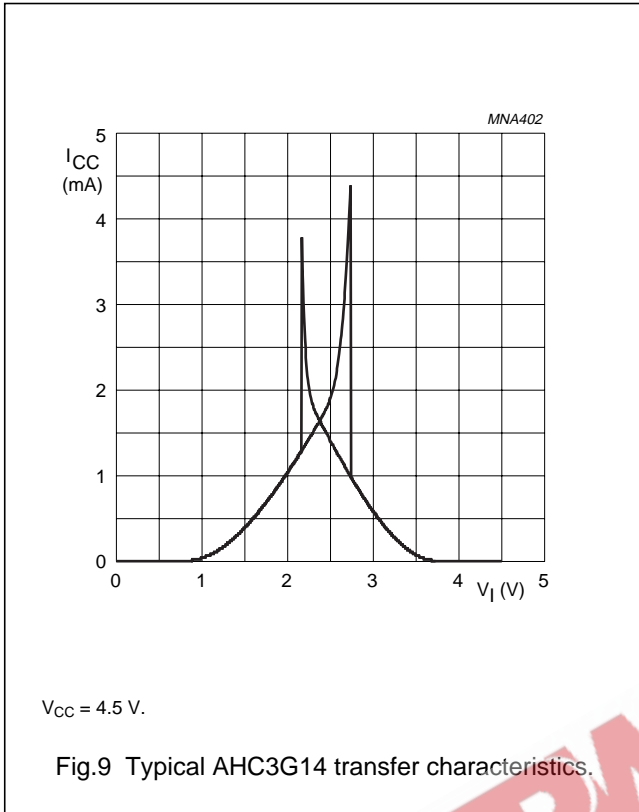
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TRANSFER CHARACTERISTIC WAVEFORMS



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AC CHARACTERISTICS

Type 74AHC3G14

GND = 0 V; $t_r = t_f \leq 3.0$ ns.

SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)	C _L (pF)				
T_{amb} = 25 °C								
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 13 and 14	3.3	15	–	4.2	–	ns
				50	–	6.0	–	ns
			3.0 to 3.6	15	–	–	12.8	ns
				50	–	–	16.3	ns
			5.0	15	–	3.2	–	ns
				50	–	4.6	–	ns
			4.5 to 5.5	15	–	–	8.6	ns
				50	–	–	10.6	ns
T_{amb} = –40 °C to +85 °C								
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 13 and 14	3.0 to 3.6	15	1.0	–	15.0	ns
				50	1.0	–	18.5	ns
			4.5 to 5.5	15	1.0	–	10.0	ns
				50	1.0	–	12.0	ns
T_{amb} = –40 °C to +125 °C								
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 13 and 14	3.0 to 3.6	15	1.0	–	16.5	ns
				50	1.0	–	20.5	ns
			4.5 to 5.5	15	1.0	–	11.0	ns
				50	1.0	–	13.5	ns

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Type 74AHCT3G14

GND = 0 V; $t_r = t_f \leq 3.0$ ns.

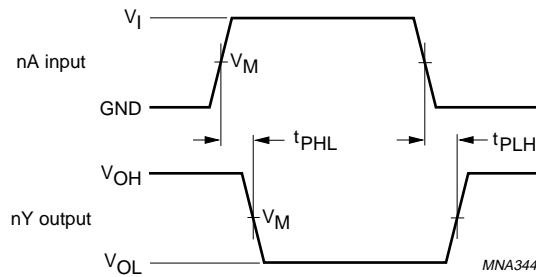
SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)	C _L (pF)				
T_{amb} = 25 °C								
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 13 and 14	5	15	–	4.1	–	ns
				50	–	5.9	–	ns
			4.5 to 5.5	15	–	–	7.0	ns
				50	–	–	8.5	ns
T_{amb} = –40 °C to +85 °C								
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 13 and 14	4.5 to 5.5	15	1.0	–	8.0	ns
				50	1.0	–	10.0	ns
T_{amb} = –40 °C to +125 °C								
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 13 and 14	4.5 to 5.5	15	1.0	–	9.0	ns
				50	1.0	–	11.0	ns

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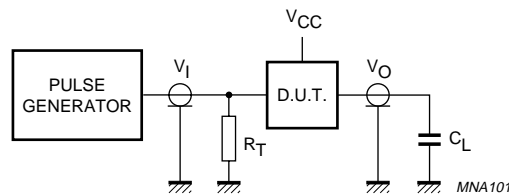
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AC WAVEFORMS



FAMILY	V _I INPUT REQUIREMENTS	V _M INPUT	V _M OUTPUT
AHC3G	GND to V _{CC}	50 % V _{CC}	50 % V _{CC}
AHCT3G	GND to 3.0 V	1.5 V	50 % V _{CC}

Fig.13 The input (nA) to output (nY) propagation delays.



Definitions for test circuit:

C_L = Load capacitance including jig and probe capacitance. (See Chapter "AC characteristics" for values).

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.14 Load circuitry for switching times.

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APPLICATION INFORMATION

The slow input rise and fall times cause additional power dissipation. This can be calculated using the following formula:

$$P_{ad} = f_i \times (t_r \times I_{CC(AV)} + t_f \times I_{CC(AV)}) \times V_{CC}$$

Where:

P_{ad} = additional power dissipation (μW);

f_i = input frequency (MHz);

t_r = input rise time (ns); 10 % to 90 %;

t_f = input fall time (ns); 90 % to 10 %;

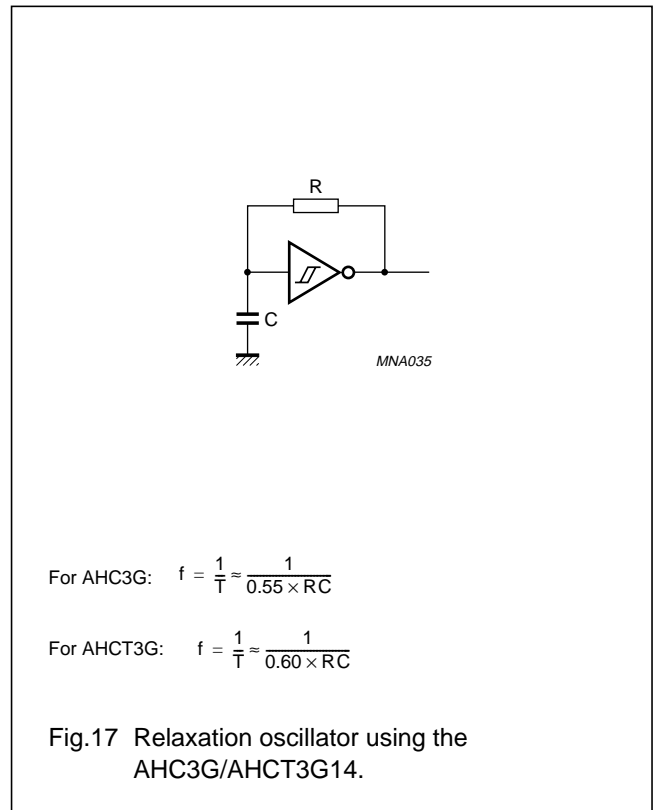
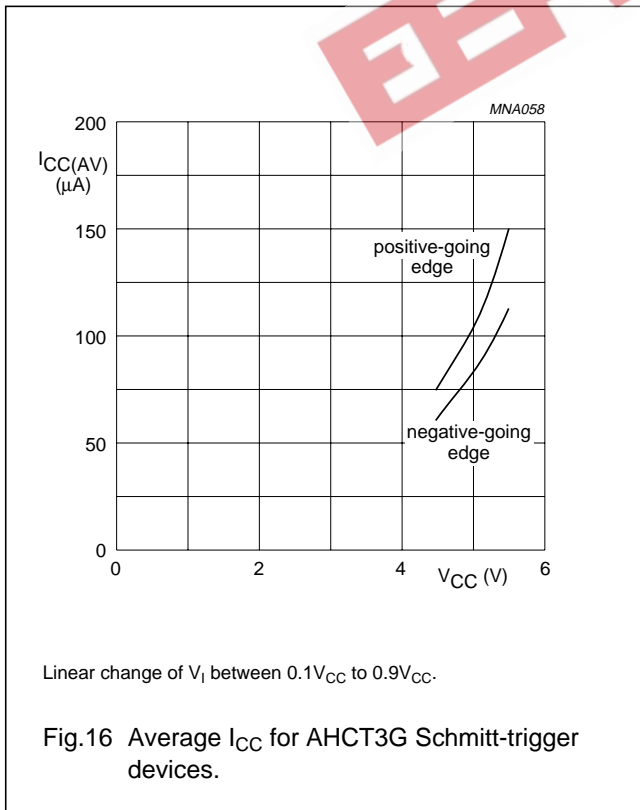
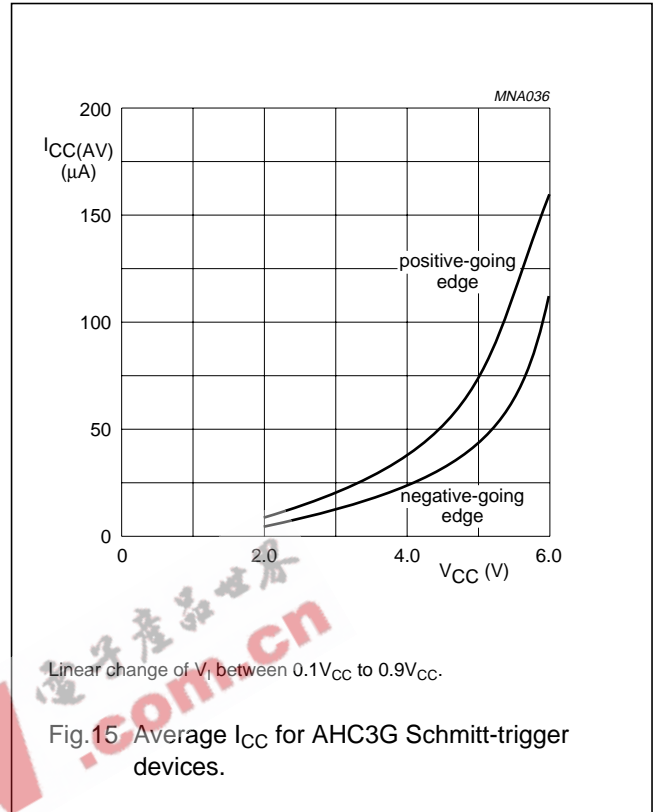
$I_{CC(AV)}$ = average additional supply current (μA).

Average I_{CC} differs with positive or negative input transitions, as shown in Figs 15 and 16.

For AHC3G/AHCT3G14 used in relaxation oscillator circuit, see Fig.17.

Remark to the application information

All values given are typical unless otherwise specified.

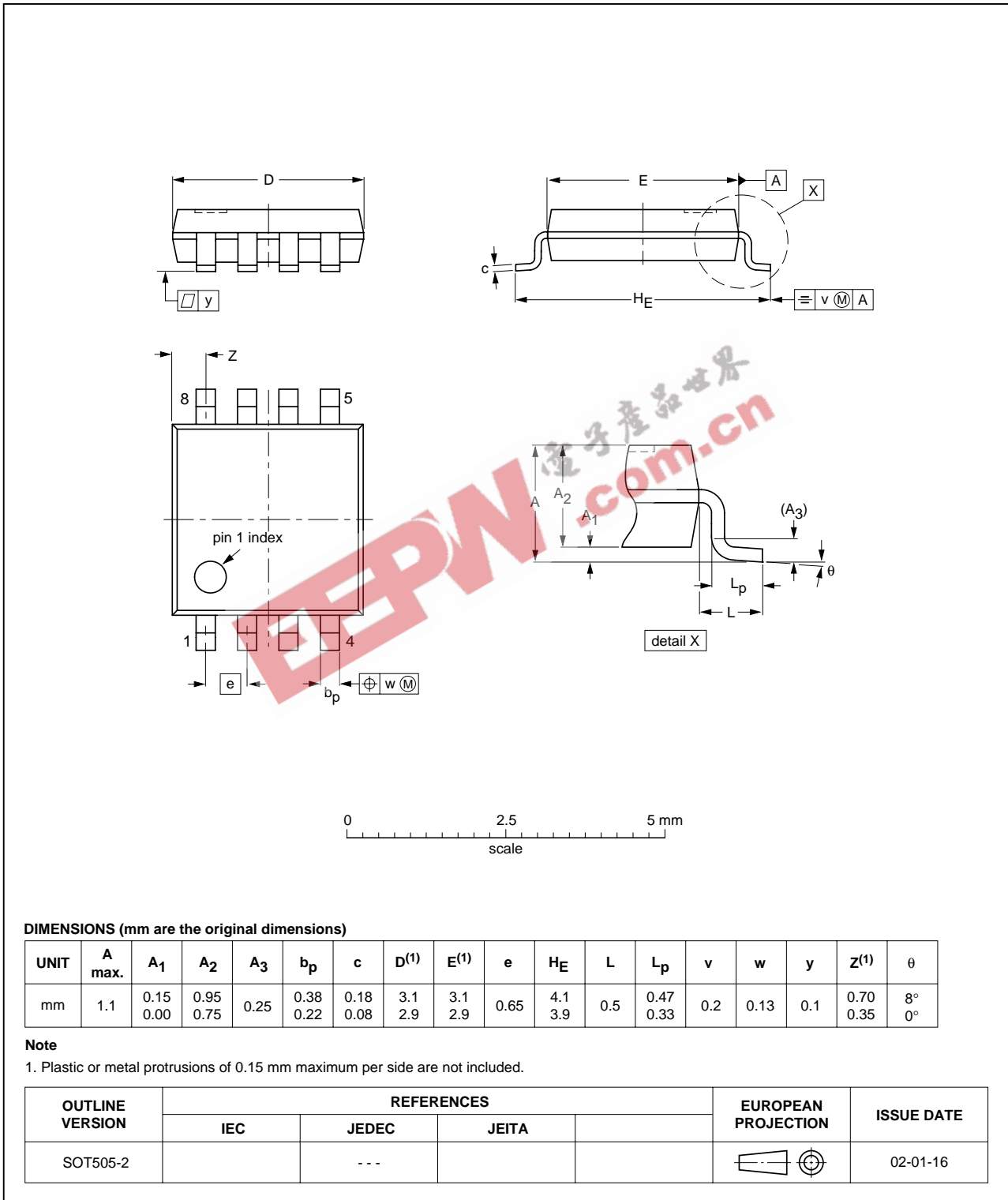


Inverting Schmitt trigger

74AHC3G14; 74AHCT3G14

PACKAGE OUTLINES

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

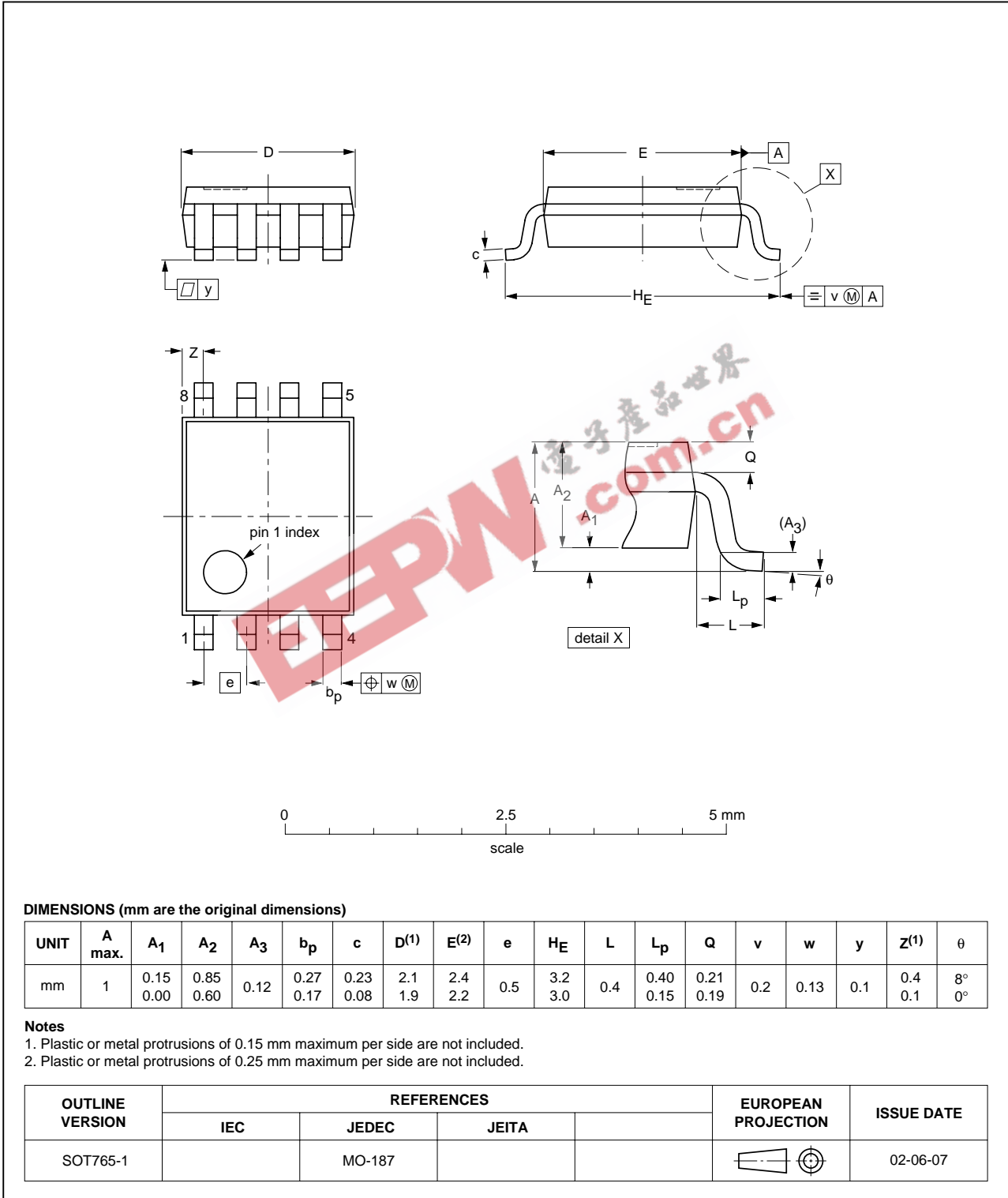


Inverting Schmitt trigger

74AHC3G14; 74AHCT3G14

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

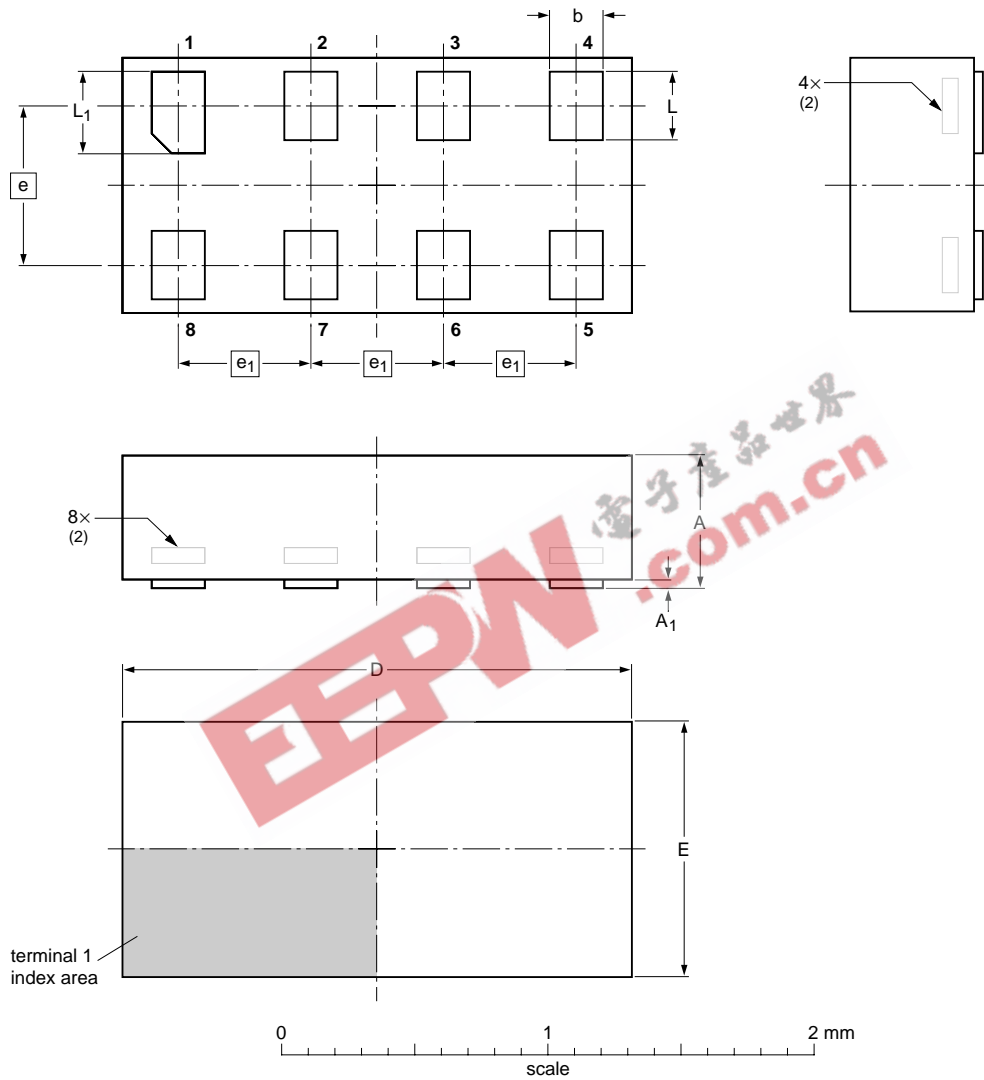


Inverting Schmitt trigger

74AHC3G14; 74AHCT3G14

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 0.95 x 1.95 x 0.5 mm

SOT833-1



DIMENSIONS (mm are the original dimensions)

UNIT	A ⁽¹⁾ max	A ₁ max	b	D	E	e	e ₁	L	L ₁
mm	0.5	0.04	0.25 0.17	2.0 1.9	1.0 0.9	0.6	0.5	0.35 0.27	0.40 0.32

Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT833-1	---	MO-252	---		04-07-15 04-07-22

Inverting Schmitt trigger

74AHC3G14; 74AHCT3G14

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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